

JAN2N5665 Information

Heisener.com

Part Number JAN2N5665

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 300V 5A TO-66

TO-213AA, TO-66-2 **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









JAN2N5665 Specifications

Manufacturer Part Number	JAN2N5665
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-213AA, TO-66-2
Series	Military, MIL-PRF-19500/455
Transistor Type	NPN
Current - Collector (Ic) (Max)	5A
Voltage - Collector Emitter Breakdown (Max)	300V
Vce Saturation (Max) @ Ib, Ic	1V @ 1A, 5A
Current - Collector Cutoff (Max)	200nA
DC Current Gain (hFE) (Min) @ Ic, Vce	25 @ 1A, 5V
Power - Max	2.5W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-213AA, TO-66-2
Supplier Device Package	TO-66 (TO-213AA)
	Report errors?

JAN2N5665 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N5665 Payment Methods



















JAN2N5665 Shipping Methods













If you have any question about JAN2N5665, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com